

**KS54HCTLS 373**  
**KS74HCTLS**

**Octal D-Type Transparent Latches**  
**with 3-State Outputs** T-46-07-05

**FEATURES**

- 8 latches in a single package
- Full parallel access for loading
- Function, pin-out, speed and drive compatibility with 54/74LS logic family
- Low power consumption characteristic of CMOS
- 3-State outputs with high drive current (I<sub>OL</sub> = 24 mA @ V<sub>OL</sub> = 0.5V) for direct bus interface
- Inputs and outputs interface directly with TTL, NMOS and CMOS devices
- Wide operating voltage range: 4.5V to 5.5V
- Characterized for operation over industrial and military temperature ranges:  
 KS74HCTLS: -40°C to +85°C  
 KS54HCTLS: -55°C to +125°C
- Package options include plastic "small outline" packages, standard plastic and ceramic 300-mil DIPs

**DESCRIPTION**

The 373 consists of 8 high-speed D-type latches coupled to 3-state output buffers with high drive current capability. It can be used in implementing buffer registers, I/O ports, bidirectional bus drivers and working registers.

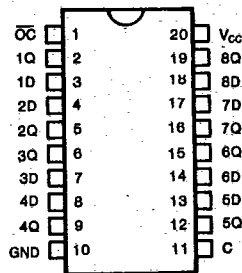
The latches are transparent: when the enable (C) is high, the Q outputs follow the data (D) inputs. When the enable is low, the outputs latch at the levels that were set up at the D inputs.

The output buffers are controlled by a common signal ( $\overline{OC}$ ) which places the outputs at a high-impedance state when it is taken high. The  $\overline{OC}$  signal does not affect the internal operations of the latches. Old data can be retained or new data can be entered while outputs are off.

These devices provide speeds and drive capability equivalent to their LSTTL counterparts and yet maintain CMOS power levels. The input and output voltage levels allow direct interface with TTL, NMOS and CMOS devices without any external components.

All inputs and outputs are protected from damage due to static discharge by internal diode clamps to V<sub>CC</sub> and ground.

**PIN CONFIGURATION**

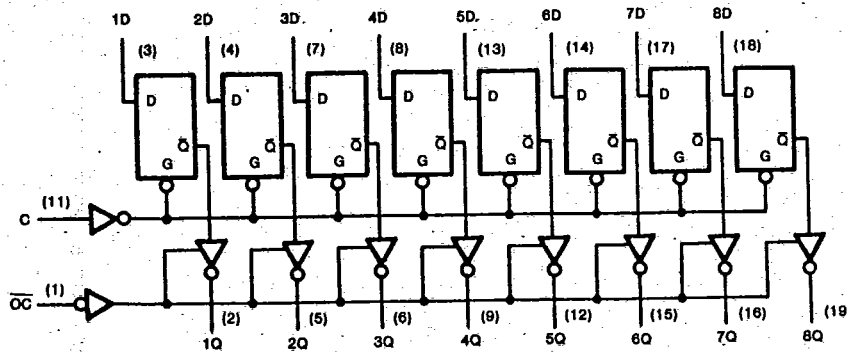


**FUNCTION TABLE**

(Each Latch)

Inputs			Output
$\overline{OC}$	Enable C	D	Q
L	H	H	H
L	H	L	L
L	L	X	Q <sub>0</sub>
H	X	X	Z

**LOGIC DIAGRAM**



**KS54HCTLS 373**  
**KS74HCTLS**

**Octal D-Type Transparent Latches**  
**with 3-State Outputs T-46-07-05**

**Absolute Maximum Ratings\***

Supply Voltage Range  $V_{CC}$  . . . . . -0.5V to +7V  
 DC Input Diode Current,  $I_{IK}$   
 ( $V_i < -0.5V$  or  $V_i > V_{CC} + 0.5V$ ) . . . . .  $\pm 20$  mA  
 DC Output Diode Current,  $I_{OK}$   
 ( $V_o < -0.5V$  or  $V_o > V_{CC} + 0.5V$ ) . . . . .  $\pm 20$  mA  
 Continuous Output Current Per Pin,  $I_o$   
 ( $-0.5V < V_o < V_{CC} + 0.5V$ ) . . . . .  $\pm 70$  mA  
 Continuous Current Through  
 $V_{CC}$  or GND pins . . . . .  $\pm 250$  mA  
 Storage Temperature Range,  $T_{stg}$  . . . . . -65°C to +150°C  
 Power Dissipation Per Package,  $P_d$ † . . . . . 500 mW

\* Absolute Maximum Ratings are those values beyond which permanent damage to the device may occur. These are stress ratings only and functional operation of the device at or beyond them is not implied. Long exposure to these conditions may affect device reliability.

† Power Dissipation temperature derating:  
 Plastic Package (N): -12mW/°C from 65°C to 85°C  
 Ceramic Package (J): -12mW/°C from 100°C to 125°C

**Recommended Operating Conditions**

Supply Voltage,  $V_{CC}$  . . . . . 4.5V to 5.5V  
 DC Input & Output Voltages\*,  $V_{IN}$ ,  $V_{OUT}$  . . . . . 0V to  $V_{CC}$   
 Operating Temperature  
 Range KS74HCTLS: -40°C to +85°C  
 KS54HCTLS: -55°C to +125°C  
 Input Rise & Fall Times,  $t_r$ ,  $t_f$  . . . . . Max 500 ns  
 \* Unused inputs must always be tied to an appropriate logic voltage level (either  $V_{CC}$  or GND)

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}=5V \pm 10\%$  Unless Otherwise Specified)

Characteristic	Symbol	Test Conditions	$T_A = 25^\circ C$			Unit	
			Typ	KS74HCTLS $T_A = -40^\circ C$ to $+85^\circ C$	KS54HCTLS $T_A = -55^\circ C$ to $+125^\circ C$		
Minimum High-Level Input Voltage	$V_{IH}$			2.0	2.0	2.0	V
Maximum Low-Level Input Voltage	$V_{IL}$			0.8	0.8	0.8	V
Minimum High-Level Output Voltage	$V_{OH}$	$V_{IN}=V_{IH}$ or $V_{IL}$ $I_o = -20\mu A$ $I_o = -6mA$	$V_{CC}$ 4.2	$V_{CC} - 0.1$ 3.98	$V_{CC} - 0.1$ 3.84	$V_{CC} - 0.1$ 3.7	V
Maximum Low-Level Output Voltage	$V_{OL}$	$V_{IN}=V_{IH}$ or $V_{IL}$ $I_o = 20\mu A$ $I_o = 12mA$ $I_o = 24mA$	0	0.1 0.26 0.39	0.1 0.33 0.5	0.1 0.4	V
Maximum Input Current	$I_{IN}$	$V_{IN}=V_{CC}$ or GND		$\pm 0.1$	$\pm 1.0$	$\pm 1.0$	$\mu A$
Maximum 3-State Leakage Current	$I_{OZ}$	Output Enable = $V_{IH}$ $V_{OUT}=V_{CC}$ or GND		$\pm 0.5$	$\pm 5.0$	$\pm 10.0$	$\mu A$
Maximum Quiescent Supply Current	$I_{CC}$	$V_{IN}=V_{CC}$ or GND $I_{OUT}=0\mu A$		8.0	80.0	160.0	$\mu A$
Additional Worst Case Supply Current	$\Delta I_{CC}$	per input pin $V_Z=2.4V$ Other Inputs: At $V_{CC}$ or GND $I_o=0$		2.7	2.9	3.0	mA

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KS54HCTLS  
KS74HCTLS **373****Octal D-Type Transparent Latches  
with 3-State Output** T-46-07-05**AC ELECTRICAL CHARACTERISTICS** (Input  $t_r, t_f < 6$  ns), HCTLS373

Characteristic	Symbol	Conditions†	$T_a = 25^\circ\text{C}$ $V_{CC} = 5.0\text{V}$		KS74HCTLS $T_a = -40^\circ\text{C to } +85^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		KS54HCTLS $T_a = -55^\circ\text{C to } +125^\circ\text{C}$ $V_{CC} = 5.0\text{V} \pm 10\%$		Unit
			Typ	Guaranteed Limits	Guaranteed Limits	Guaranteed Limits			
Maximum Propagation Delay, D to Q	$t_{PLH}$	$C_L = 50\text{pF}$ $C_L = 150\text{pF}$	14 17	18 21	23 28	27 33			ns
	$t_{PHL}$	$C_L = 50\text{pF}$ $C_L = 150\text{pF}$	14 17	18 21	23 28	27 33			
Maximum Propagation Delay, C to any Q	$t_{PLH}$	$C_L = 50\text{pF}$ $C_L = 150\text{pF}$	22 25	30 33	37 42	45 51			ns
	$t_{PHL}$	$C_L = 50\text{pF}$ $C_L = 150\text{pF}$	22 25	30 33	37 42	45 51			
Maximum Output Enable Time, $\overline{OC}$ to any Q	$t_{PZH}$	$R_L = 1\text{k}\Omega$ $C_L = 50\text{pF}$ $C_L = 150\text{pF}$	24 27	32 35	40 45	48 54			ns
	$t_{PZL}$	$C_L = 50\text{pF}$ $C_L = 150\text{pF}$	24 27	32 35	40 45	48 54			
Maximum Output Disable Time, $\overline{OC}$ to any Q	$t_{PHZ}$	$R_L = 1\text{k}\Omega$	19	25	31	37			ns
	$t_{PLZ}$	$C_L = 50\text{pF}$	19	25	31	37			
Minimum Pulse Width, C High	$t_w$		6	10	12	15			ns
Minimum Setup Time, D before $C\downarrow$	$t_{su}$		2	3	4	5			ns
Minimum Hold Time, D after $C\downarrow$	$t_h$		6	10	12	15			ns
Maximum Input Capacitance	$C_{IN}$		5						pF
Maximum Output Capacitance	$C_{OUT}$	Output Disabled	10						pF
Power Dissipation Capacitance* (per latch)	$C_{PD}$	$\overline{OC} = V_{CC}$	5						pF
		$\overline{OC} = \text{GND}$	30						

\*  $C_{PD}$  determines the no-load dynamic power dissipation:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

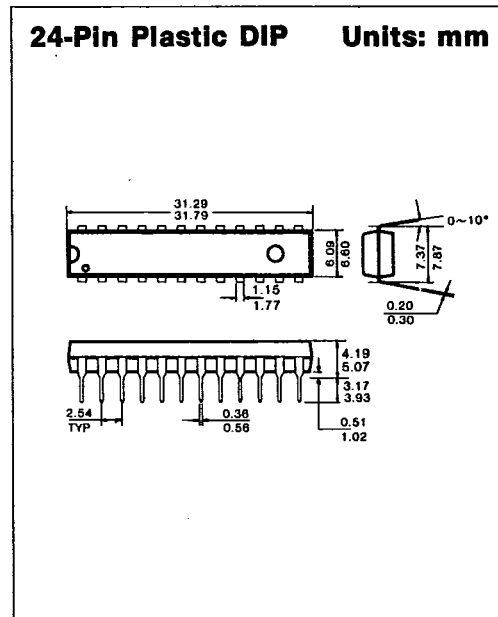
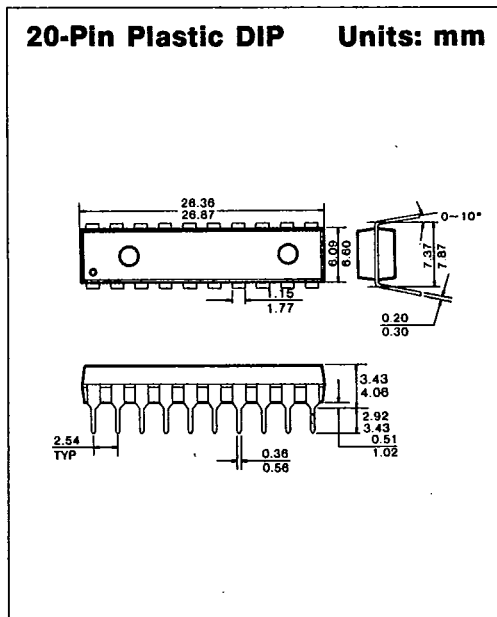
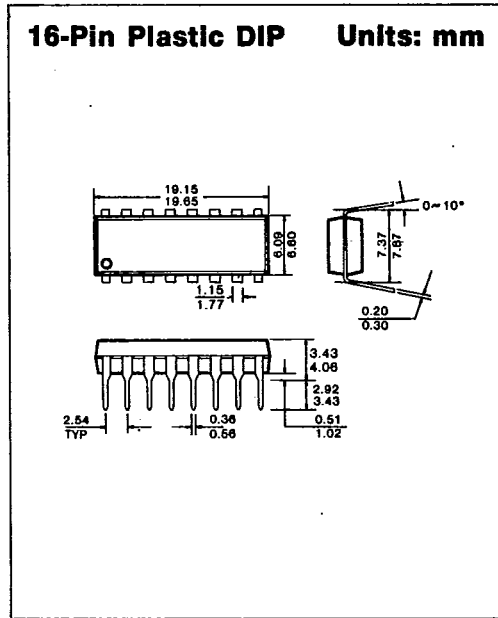
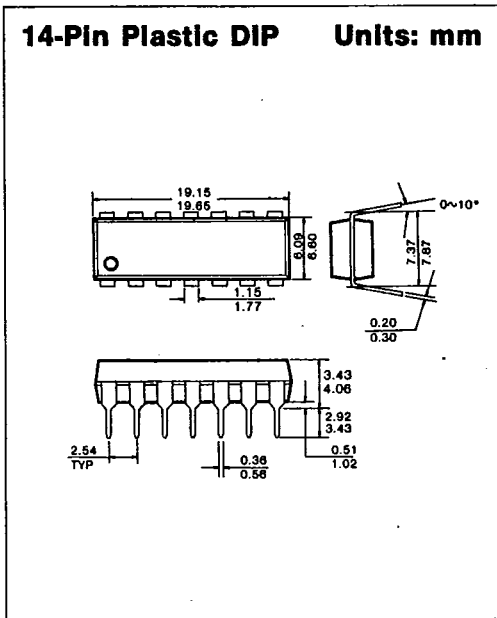
† For AC switching test circuits and timing waveforms see section 2.



**PACKAGE DIMENSIONS**

T-90-20

**1. PLASTIC PACKAGES**



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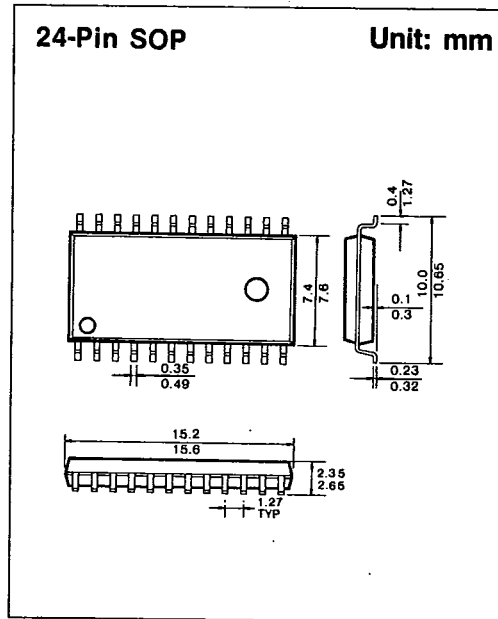
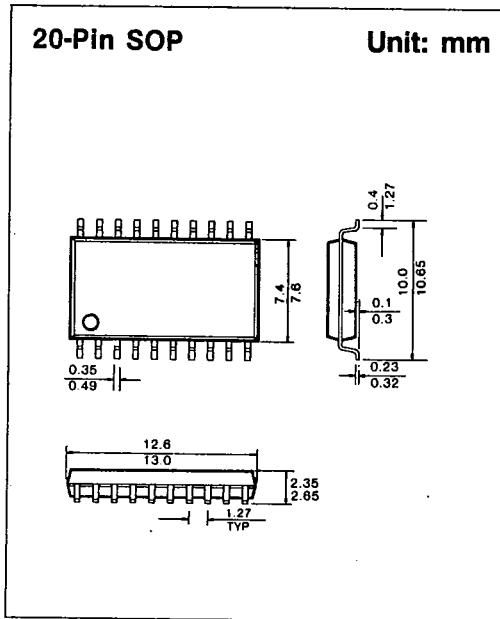
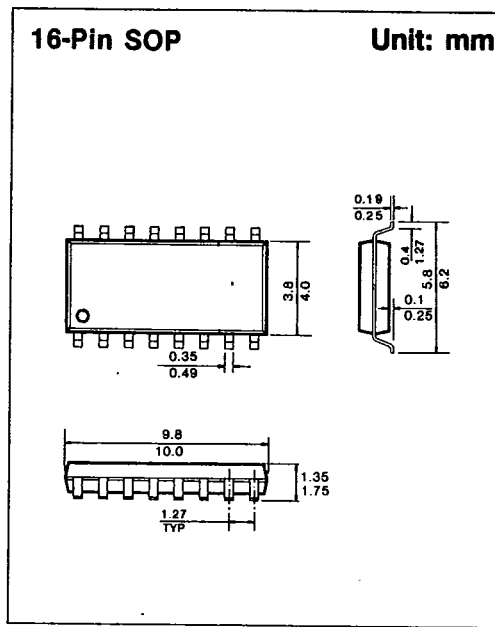
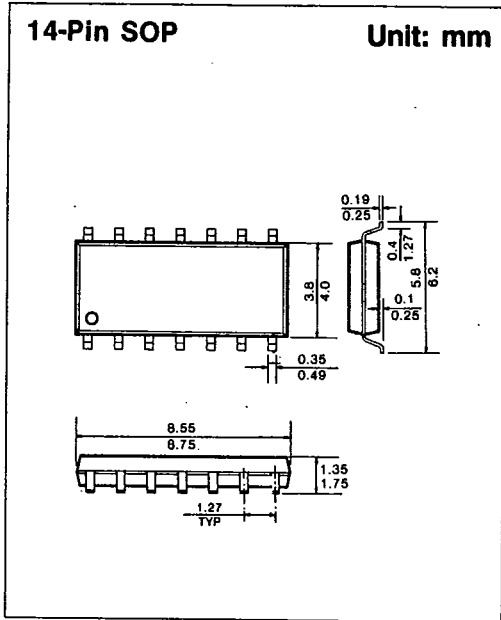
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**PACKAGE DIMENSIONS**

T-90-20



**PACKAGE DIMENSIONS**

T-90-20

**2. CERAMIC PACKAGES**

**14-Pin Ceramic DIP Units: mm**

Dim	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B <sub>1</sub>	1.40	1.78
C	0.20	0.38
D	18.16	19.56
E	8.10	7.49
E <sub>1</sub>	7.82	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	1.91	2.29

**16-Pin Ceramic DIP Units: mm**

Dim	Millimeters	
	Min	Max
A	—	5.08
B	0.38	0.58
B <sub>1</sub>	1.40	1.78
C	0.20	0.38
D	19.05	19.94
E	8.10	7.49
E <sub>1</sub>	7.82	10.03
F	2.54	
L	3.18	4.19
Q	0.51	1.02
S	0.51	1.14

**20-Pin Ceramic DIP Units: mm**

Dim	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B <sub>1</sub>	1.14	1.52
C	0.20	0.38
D	25.78	26.33
E	8.10	8.60
E <sub>1</sub>	7.77	7.95
F	2.54	
L	3.73	4.01
Q	0.38	0.89
S	0.51	1.14

**24-Pin Ceramic DIP Units: mm**

Dim	Millimeters	
	Min	Max
A	4.06	5.08
B	0.38	0.53
B <sub>1</sub>	1.14	1.52
C	0.20	0.38
D	31.50	32.84
E	7.24	7.75
E <sub>1</sub>	7.77	7.98
F	2.54	
L	3.73	4.01
Q	0.508	1.776
S	1.85	1.93

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